

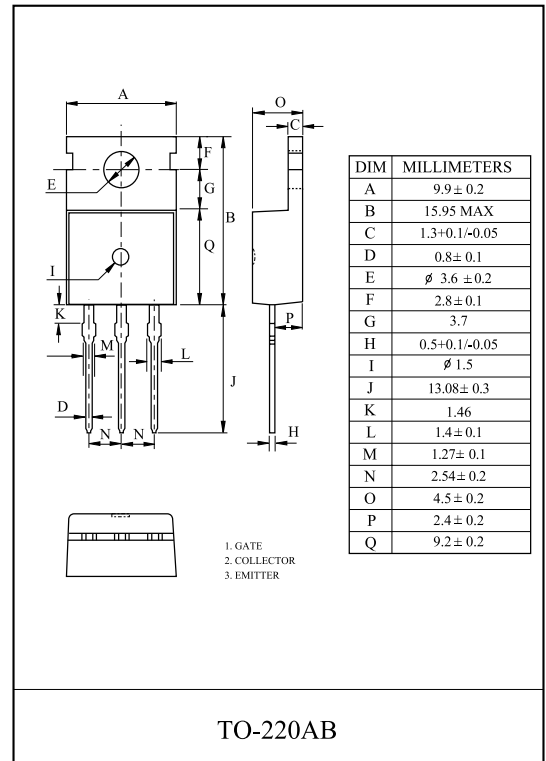
## General Description

KEC Field Stop Trench IGBTs offer low switching losses, high energy efficiency and short circuit ruggedness.

It is designed for applications such as motor control, uninterrupted power supplies(UPS), general inverters.

## FEATURES

- High speed switching
- High ruggedness, temperature stable behavior
- Short Circuit Withstand Times 10us(@ $T_c=100$  )
- Extremely enhanced avalanche capability



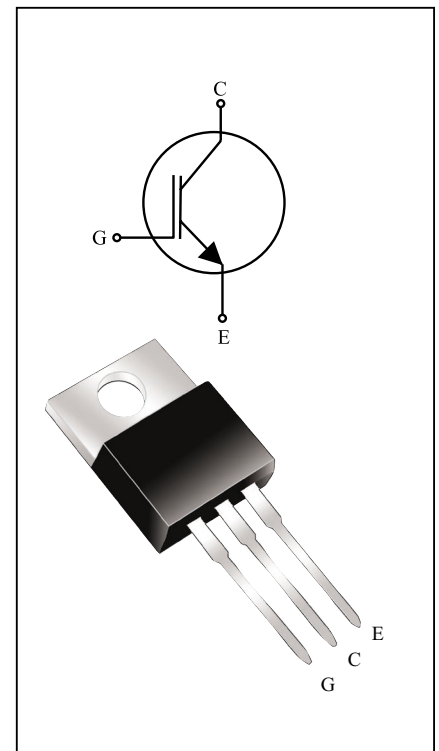
## MAXIMUM RATING (Ta=25 )

CHARACTERISTIC		SYMBOL	RATING	UNIT
Collector-Emitter Voltage		$V_{CES}$	600	V
Gate-Emitter Voltage		$V_{GES}$	± 20	V
Collector Current	@ $T_c=25$	$I_C$	60	A
	@ $T_c=100$		30	A
Pulsed Collector Current		$I_{CM}^*$	90	A
Maximum Power Dissipation	@ $T_c=25$	$P_D$	178	W
	@ $T_c=100$		71	W
Maximum Junction Temperature		$T_j$	150	
Storage Temperature Range		$T_{stg}$	-55 to + 150	

\*Repetitive rating : Pulse width limited by max. junction temperature

## THERMAL CHARACTERISTIC

CHARACTERISTIC	SYMBOL	MAX.	UNIT
Thermal Resistance, Junction to Case (IGBT)	$R_{thJC}$	0.7	/W
Thermal Resistance, Junction to Ambient	$R_{thJA}$	40	/W



# KGF30N60PA

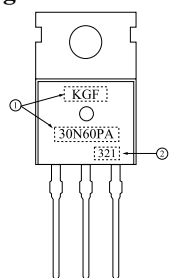
## ELECTRICAL CHARACTERISTICS (Ta=25 °C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT	
Static							
Collector-Emitter Breakdown Voltage	$BV_{CES}$	$V_{GE}=0V, I_C=250\mu A$	600	-	-	V	
Collector Cut-off Current	$I_{CES}$	$V_{GE}=0V, V_{CE}=600V$	-	-	250	$\mu A$	
Gate Leakage Current	$I_{GES}$	$V_{CE}=0V, V_{GE}=\pm 20V$	-	-	$\pm 100$	nA	
Gate Threshold Voltage	$V_{GE(th)}$	$V_{GE}=V_{CE}, I_C=3mA$	4.5	5.5	7.0	V	
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$V_{GE}=15V, I_C=30A$	-	1.65	2.1	V	
		$V_{GE}=15V, I_C=60A$	-	2.25	-	V	
		$V_{GE}=15V, I_C=30A, T_C = 125$	-	1.85	-	„V	
Dynamic							
Total Gate Charge	$Q_g$	$V_{CC}=300V, V_{GE}=15V, I_C=30A$	-	120	-	nC	
Gate-Emitter Charge	$Q_{ge}$		-	20	-	nC	
Gate-Collector Charge	$Q_{gc}$		-	60	-	nC	
Turn-On Delay Time	$t_{d(on)}$	$V_{CC}=300V, I_C=30A, V_{GE}=15V, R_G=10$ Inductive Load, $T_C = 25$ (Note 1)	-	40	-	ns	
Rise Time	$t_r$		-	35	-	ns	
Turn-Off Delay Time	$t_{d(off)}$		-	160	-	ns	
Fall Time	$t_f$		-	35	-	ns	
Turn-On Switching Loss	$E_{on}$		-	0.7	-	mJ	
Turn-Off Switching Loss	$E_{off}$		-	0.45	-	mJ	
Total Switching Loss	$E_{ts}$		-	1.15	-	mJ	
Turn-On Delay Time	$t_{d(on)}$		$V_{CC}=300V, I_C=30A, V_{GE}=15V, R_G=10$ Inductive Load, $T_C = 125$ (Note 1)	-	40	-	ns
Rise Time	$t_r$			-	35	-	ns
Turn-Off Delay Time	$t_{d(off)}$			-	180	-	ns
Fall Time	$t_f$	-		45	-	ns	
Turn-On Switching Loss	$E_{on}$	-		0.8	-	mJ	
Turn-Off Switching Loss	$E_{off}$	-		0.6	-	mJ	
Total Switching Loss	$E_{ts}$	-		1.4	-	mJ	
Input Capacitance	$C_{ies}$	$V_{CE}=30V, V_{GE}=0V, f=1MHz$	-	2350	-	pF	
Output Capacitance	$C_{oes}$		-	160	-	pF	
Reverse Transfer Capacitance	$C_{res}$		-	95	-	pF	
Short Circuit Withstand Time	$t_{sc}$	$V_{CC}=300V, V_{GE}=15V, T_C=100$	10	-	-	$\mu s$	

Note 1 : Energy loss include tail current and diode reverse recovery.

Diode is used KGF30N60KDA

### Marking



○ PRODUCT NAME  
○ LOT NO

# KGF30N60PA

## Typical Performance Characteristics

Fig 1. Saturation Voltage Characteristics

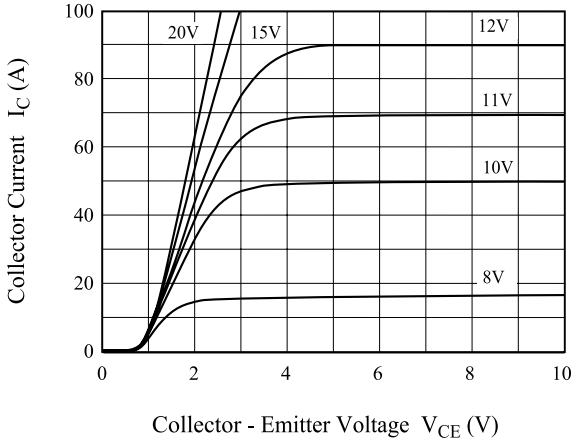


Fig 2. Saturation Voltage Characteristics

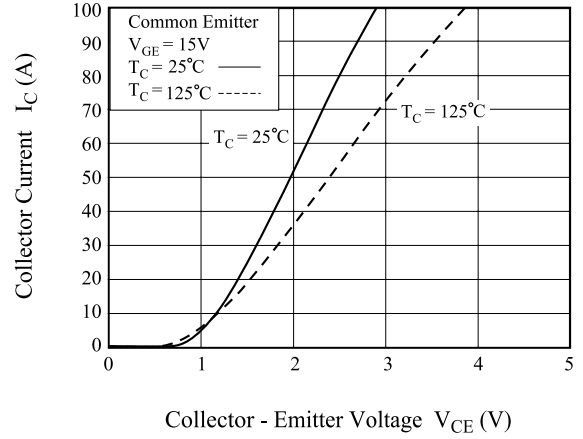


Fig 3. Saturation Voltage vs. Case Temperature

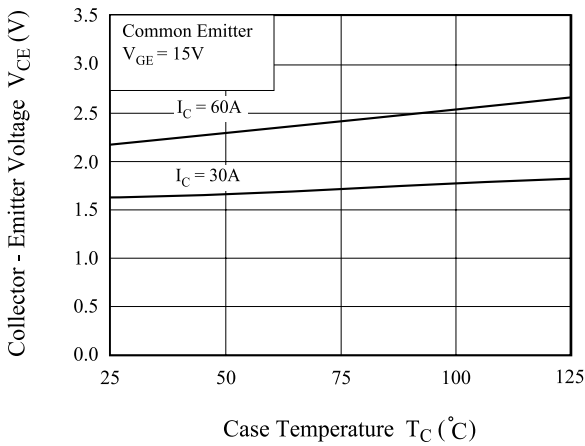


Fig 4. Saturation Voltage vs.  $V_{GE}$

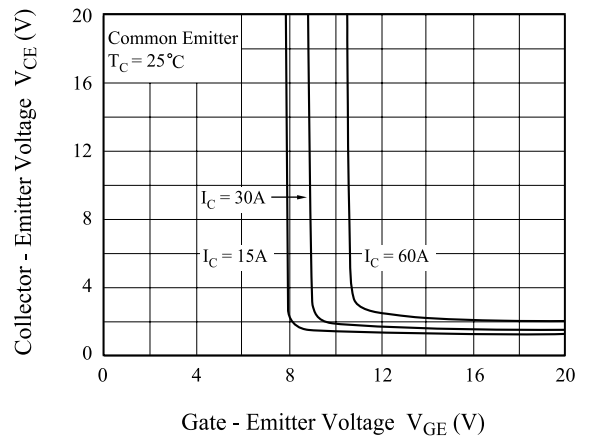


Fig 5. Saturation Voltage vs.  $V_{GE}$

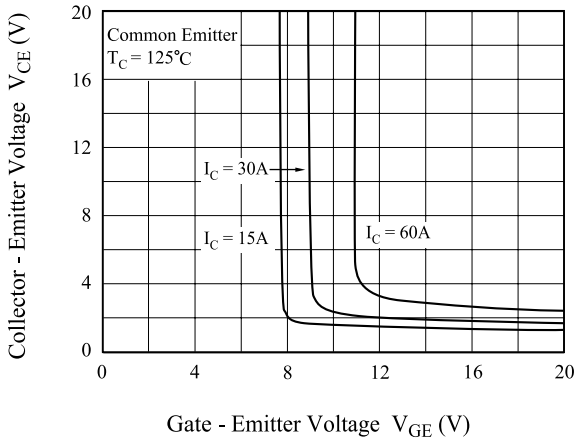
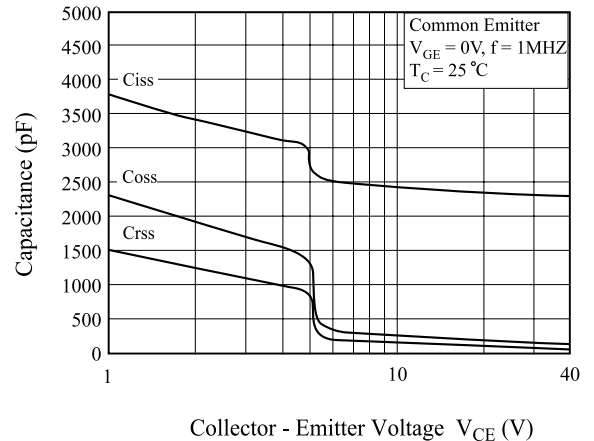


Fig 6. Capacitance Characteristics



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## Typical Performance Characteristics (Continued)

Fig 7. Turn-On Characteristics vs. Gate Resistance

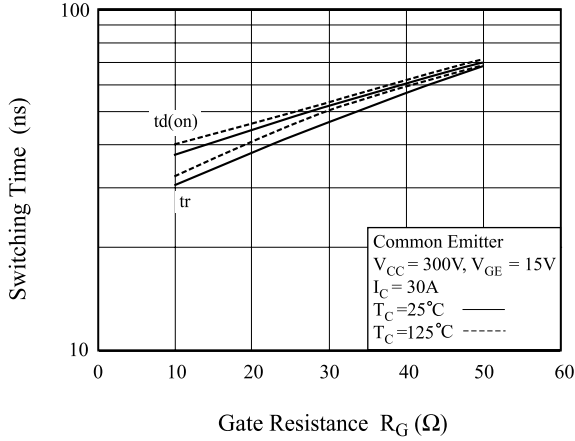


Fig 8. Turn-Off Characteristics vs. Gate Resistance

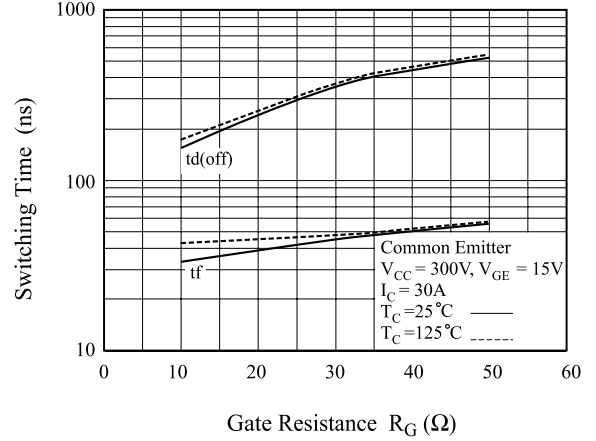


Fig 9. Switching Loss vs. Gate Resistance

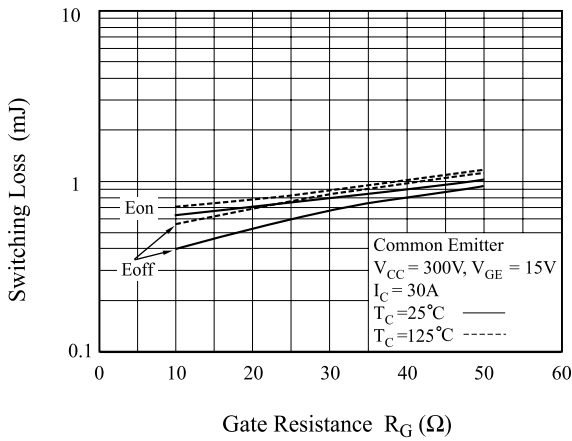


Fig 10. Turn-On Characteristics vs. Collector Current

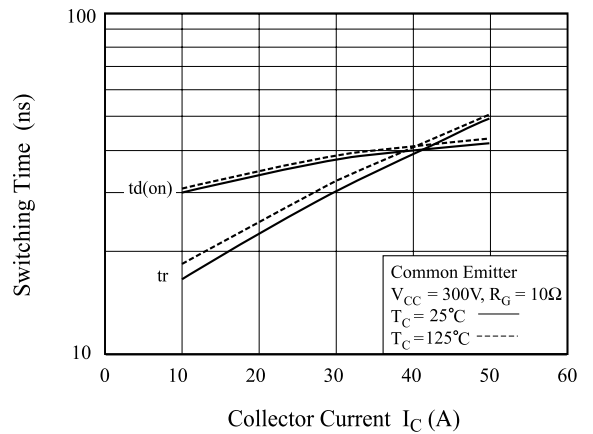


Fig 11. Turn-Off Characteristics vs. Collector Current

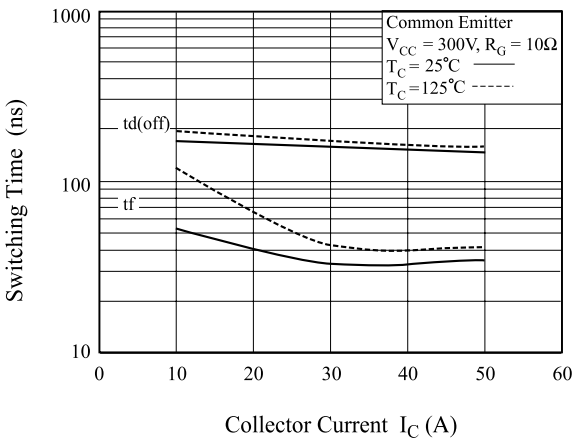
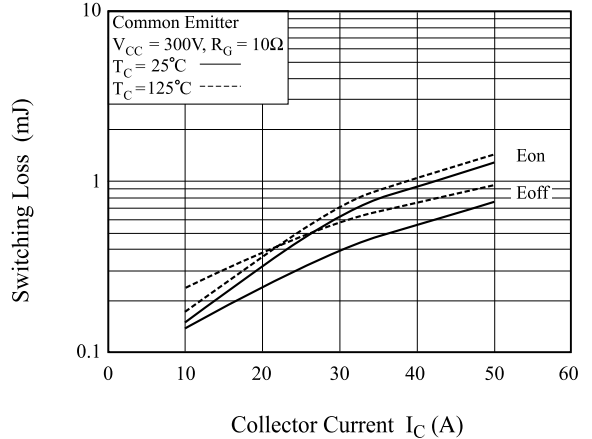


Fig 12. Switching Loss vs. Collector Current



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## Typical Performance Characteristics (Continued)

Fig 13. Gate Charge Characteristics

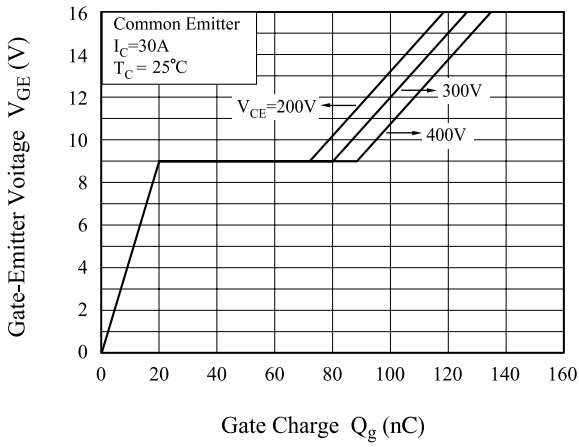


Fig 14. SOA Characteristics

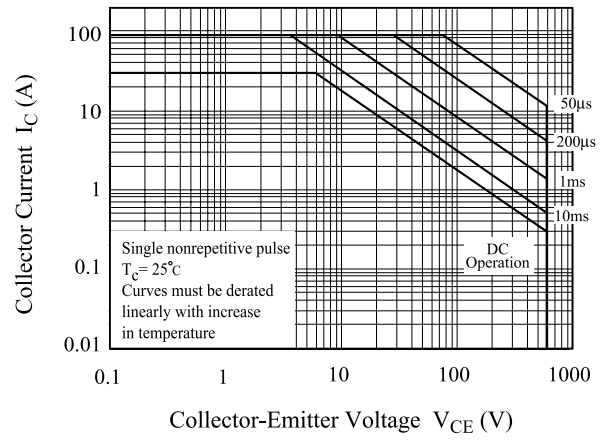


Fig 15. Turn-Off SOA

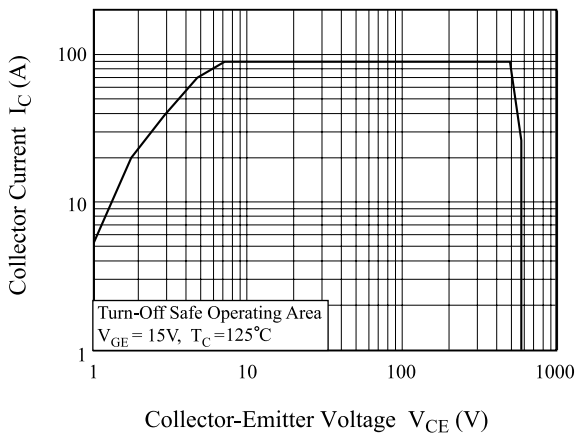
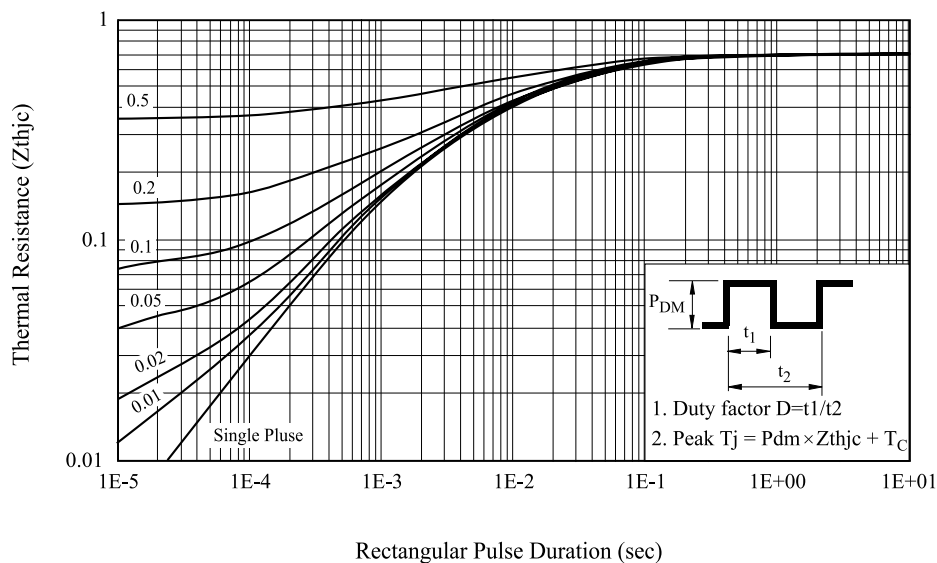


Fig 16. Transient Thermal Impedance of IGBT



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Fig 17. Switching Test Circuit

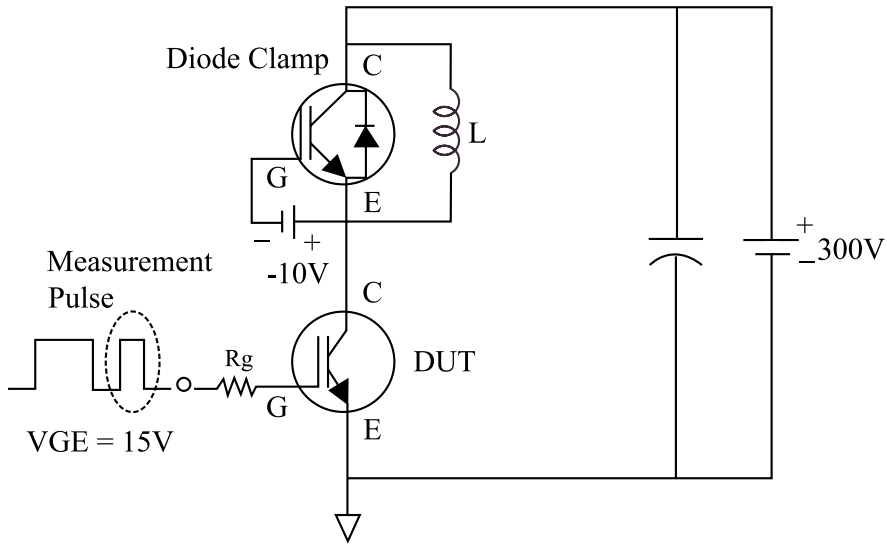


Fig 18. Definition Switching Time & Loss

